

P CHANNEL MOSFET, -20V, Transistor Polarity:P Channel, Continuous Drain Current Id:-7.8A, Drain Source Voltage Vds:-20V, On Resistance Rds(on):0.027ohm, Rds(on) Test Voltage Vgs:-4.5V, Threshold Voltage Vgs:-880mV

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	SOIC-8
Product Type	Transistors
RoHS	Pb-free Halide free
Lifecycle	



Images are for reference only

Please submit RFQ for NTMD6P02R2G or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

Power MOSFET 6 A, 20 V, P-Channel SOIC-8, Dual

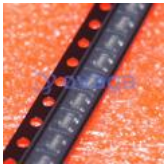
## Features

- Ultra Low RDS(on)
- Higher Efficiency Extending Battery Life
- Logic Level Gate Drive
- Miniature Dual SO-8 Surface Mount Package
- Diode Exhibits High Speed, Soft Recovery
- Avalanche Energy Specified
- SO-8 Mounting Information Provided
- Pb-Free Packages are Available

## Application

ONSEMI

## Related Products



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SOT-23



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TO-247